# NSN 5961-00-103-1642

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#### **Inclosure Material:**

Metal

#### **Overall Length:**

Between 0.065 inches and 0.085 inches

#### **Overall Diameter:**

Between 0.209 inches and 0.230 inches

#### Internal Configuration:

Junction contact

#### **Mounting Method:**

Terminal

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

140.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, dc

#### **Current Rating Per Characteristic:**

Between 0.50 amperes source cutoff current and 2.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

4.0 watts small-signal input power, common-collector preset

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Test Data Document:**

13499-352-0735 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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